3.3V CMOS 16-BIT BUS TRANSCIEVER WITH 3-STATE OUTPUTS

AND BUS-HOLD

IDT74ALVCHR162245

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- $VCC = 2.5V \pm 0.2V$
- CMOS power levels (0.4 w typ. static)
- · Rail-to-Rail output swing for increased noise margin
- · Available in TSSOP package

DRIVE FEATURES:

- · Balanced Output Drivers: ±12mA
- · Low Switching Noise

APPLICATIONS:

- · 3.3V high speed systems
- · 3.3V and lower voltage computing systems

DESCRIPTION:

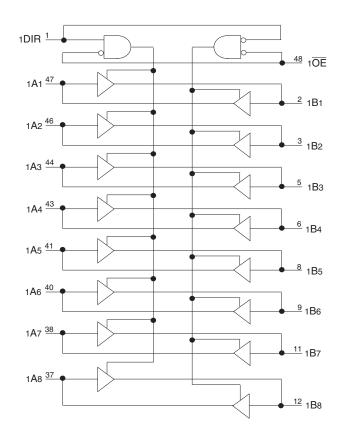
This 16-bit bus transceiver is built using advanced dual metal CMOS technology. The ALVCHR162245 device is designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements.

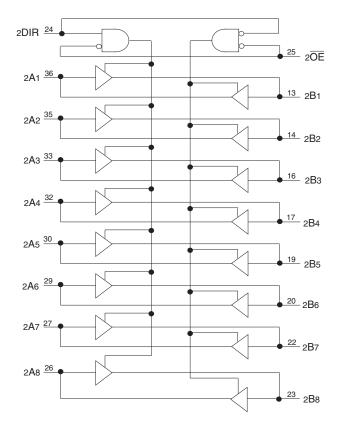
This device can be used as two 8-bit transceivers or one 16-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

The ALVCHR162245 has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been designed to drive ± 12 mA at the designated threshold levels.

The ALVCHR162245 has "bus-hold" which retains the inputs' last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



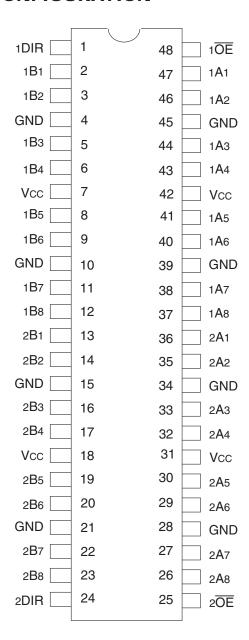


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INDUSTRIAL TEMPERATURE RANGE

SEPTEMBER 2016

PIN CONFIGURATION



TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +4.6	٧
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	٧
Tstg	Storage Temperature	-65 to +150	°C
lout	DC Output Current	-50 to +50	mA
lıĸ	Continuous Clamp Current, VI < 0 or VI > VCC	±50	mA
Іок	Continuous Clamp Current, Vo < 0	-50	mA
lcc lss	Continuous Current through each Vcc or GND	±100	mA

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	5	7	pF
Соит	Output Capacitance	Vout = 0V	7	9	pF
CI/O	I/O Port Capacitance	VIN = 0V	7	9	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description	
xŌĒ	Output Enable Inputs (Active LOW)	
DIR	Direction Control Inputs	
xAx ⁽¹⁾ Side A Inputs or 3-State Outputs		
xBx ⁽¹⁾	Side B Inputs or 3-State Outputs	

NOTE:

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (EACH 8-BIT SECTION)(1)

Inp	outs	
хŌĒ	xDIR	Outputs
L	L	Bus B data to A bus
L	Н	Bus A data to B bus
Н	Х	High Z State

NOTE:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
 - X = Don't Care
 - Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Condit	tions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		T -	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
Iн	Input HIGH Current	Vcc = 3.6V	VI = VCC	_	_	±5	μA
lıL	Input LOW Current	Vcc = 3.6V	Vı = GND	_	_	±5	μA
lozн	High Impedance Output Current	Vcc = 3.6V	Vo = Vcc	_	_	±10	μA
lozl	(3-State Output pins)		Vo = GND	-	_	±10	
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		_	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		T -	100	_	mV
ICCL ICCH ICCZ	Quiescent Power Supply Current	Vcc = 3.6V Vin = GND or Vcc		_	0.1	40	μΑ
Δlcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other in	nputs at Vcc or GND	_	_	750	μΑ

NOTE:

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3V	Vı = 2V	– 75	_		μΑ
IBHL			Vı = 0.8V	75	_	_	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	Vı = 1.7V	– 45	_	_	μΑ
IBHL			Vı = 0.7V	45	_	ı	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	VI = 0 to 3.6V	_	_	±500	μA
IBHLO							

NOTES:

- 1. Pins with Bus-Hold are identified in the pin description.
- 2. Typical values are at Vcc = 3.3V, +25°C ambient.

^{1.} Typical values are at Vcc = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
Voн	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Iон = - 0.1mA	Vcc - 0.2	_	V
		Vcc = 2.3V	Iон = -4mA	1.9	_	
			Iон = -6mA	1.7	_	
		Vcc = 2.7V	Iон = -4mA	2.2	_	
			Iон = -8mA	2	_	
		Vcc = 3V	Iон = -6mA	2.4	_	
			Iон = - 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 4mA	_	0.4	
			IoL = 6mA	_	0.55	
		Vcc = 2.7V	IoL = 4mA	_	0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3V	IoL = 6mA	_	0.55	
			IoL = 12mA	_	0.8	

NOTE:

OPERATING CHARACTERISTICS, TA = 25°C

			$Vcc = 2.5V \pm 0.2V$	$VCC = 3.3V \pm 0.3V$	
Symbol	Parameter	Test Conditions	Typical	Typical	Unit
CPD	Power Dissipation Capacitance Outputs enabled	CL = 0pF, f = 10Mhz	24	32	pF
CPD	Power Dissipation Capacitance Outputs disabled		4	5	

SWITCHING CHARACTERISTICS(1)

		Vcc = 2.5	V ± 0.2V	Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	1	4.9	_	4.7	1	4.2	ns
tPHL	xAx to xBx or xBx to xAx							
tpzh	Output Enable Time	1	6.8	_	6.7	1	5.6	ns
tPZL	xOE to xAx or xBx							
tphz	Output Disable Time	1	6.3	_	5.7	1	5.5	ns
tPLZ	xOE to xAx or xBx							
tsk(o)	Output Skew ⁽²⁾	_	_	_	_	_	500	ps

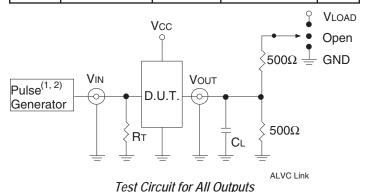
NOTES:

- 1. See TEST CIRCUITS AND WAVEFORMS. TA = -40°C to + 85°C.
- 2. Skew between any two outputs of the same package and switching in the same direction.

^{1.} VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to + 85°C.

TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc ⁽¹⁾ =2.7V	$Vcc^{(2)} = 2.5V \pm 0.2V$	Unit
VLOAD	6	6	2 x Vcc	٧
VIH	2.7	2.7	Vcc	٧
VT	1.5	1.5	Vcc/2	V
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

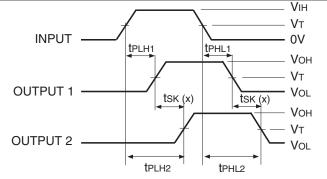
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

NOTES:

- 1. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open



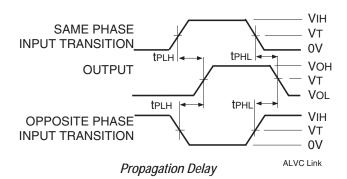
tsk(x) = |tPLH2 - tPLH| of tPHL2 - tPHL|1

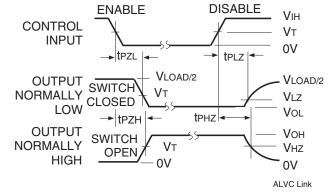
ALVC Link

Output Skew - tsk(x)

NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.

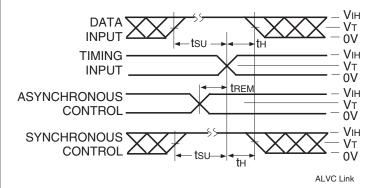




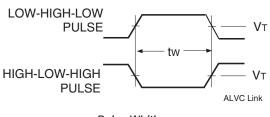
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

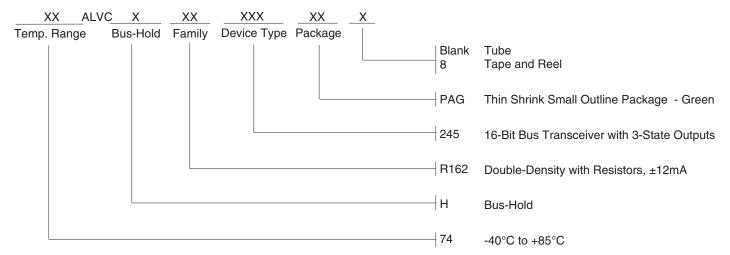


Set-up, Hold, and Release Times



Pulse Width

ORDERING INFORMATION



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